



MMDT5401

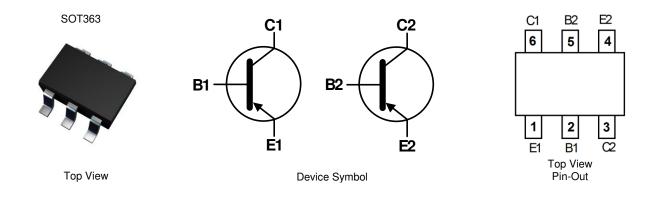
150V DUAL PNP SMALL SIGNAL TRANSISTOR IN SOT363

Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (MMDT5551)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>MMDT5401Q</u>)

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.006 grams (Approximate)



Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
MMDT5401-7-F	K4M	7	8	3,000

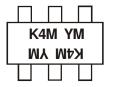
Notes:	 No purposely adde 	ed lead. Fully EU Directive 2002	/95/EC (RoHS), 2011/65/EU (RoHS	S 2) & 2015/863/EU (RoHS 3) comp	oliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



K4M = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key

Year	2017	20	18	2019	2020	20	21	2022	2023	20	24	2025
Code	E	F	=	G	Н		I	J	K	l	-	М
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-160	V
Collector-Emitter Voltage	VCEO	-150	V
Emitter-Base Voltage	V _{EBO}	-6	V
Continuous Collector Current	Ι _C	-200	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Dower Dissignation	(Note 5)	D	200	mW	
Power Dissipation	(Notes 6 & 7)	PD	320	IIIVV	
Thermal Desistance Junction to Ambient	(Note 5)	D	625		
Thermal Resistance, Junction to Ambient	(Notes 6 & 7)	R _{0JA}	390	°C/W	
Thermal Resistance, Junction to Case	(Note 8)	R _{θJC}	140		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition	
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage	BV _{CBO}	-160	_	_	V	$I_{C} = -100 \mu A, I_{E} = 0$	
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-150	_		V	$I_{C} = -1mA, I_{B} = 0$	
Emitter-Base Breakdown Voltage	BV _{EBO}	-6	_		V	$I_E = -100 \mu A, I_C = 0$	
Collector-Base Cutoff Current				-50	nA	$V_{CB} = -120V, I_E = 0$	
Collector-Base Cuton Current	I _{CBO}	_	_	-50	μA	$V_{CB} = -120V, I_E = 0, T_A = +100^{\circ}C$	
Base-Emitter Cutoff Current	I _{EBO}	_	_	-50	nA	$V_{EB} = -5V, I_{C} = 0$	
ON CHARACTERISTICS (Note 9)							
		50				$I_{C} = -1.0mA, V_{CE} = -5.0V$	
DC Current Gain	h _{FE}	60	—	240	—	$I_{C} = -10mA, V_{CE} = -5.0V$	
		50				$I_{C} = -50 \text{mA}, V_{CE} = -5.0 \text{V}$	
Collector-Emitter Saturation Voltage	V		_	-0.2	v	$I_{C} = -10mA, I_{B} = -1.0mA$	
	V _{CE(SAT)}			-0.5	v	$I_{C} = -50mA, I_{B} = -5.0mA$	
Base-Emitter Saturation Voltage		SAT) —	_	-1.0	V	$I_{C} = -10mA, I_{B} = -1.0mA$	
Dase-Enniter Saturation voltage	V _{BE(SAT)}					$I_{C} = -50mA, I_{B} = -5.0mA$	
SMALL SIGNAL CHARACTERISTICS							
Output Capacitance	Cobo	_	_	6.0	pF	$V_{CB} = -10V, f = 1.0MHz, I_E = 0$	
Small Signal Current Gain	h _{fe}	40	_	260		$I_{C} = -1mA, V_{CE} = -10V, f = 1.0MHz$	
Current Gain-Bandwidth Product	fT	100		300	MHz	$I_{C} = -10mA, V_{CE} = -10V, f = 100MHz$	
Noise Figure	NF	_	—	8.0	dB	$\label{eq:Vce} \begin{split} V_{CE} &= -5.0V, \ I_C = -200 \mu A, \\ R_S &= 10\Omega, \ f = 1.0 kHz \end{split}$	

Notes: 5. For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is mounted 25mm X 25mm 2oz copper.

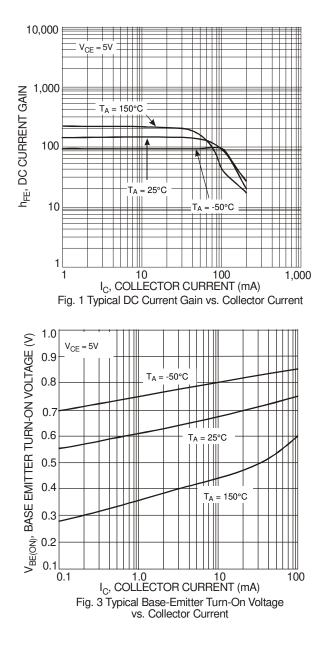
7. Maximum combined dissipation.

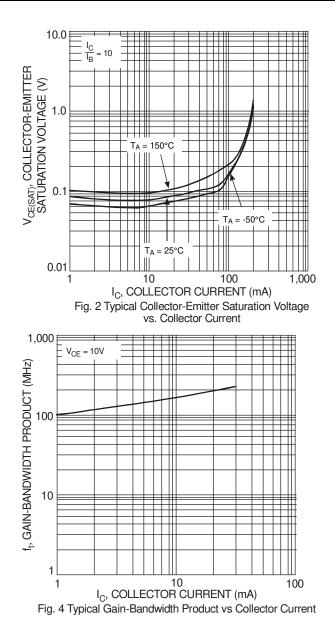
8. Thermal resistance from junction to the top of package.

9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

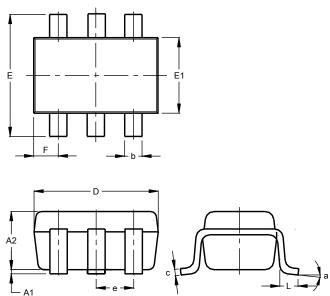






Package Outline Dimensions

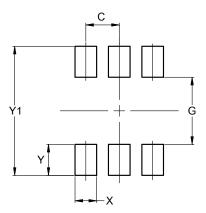
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.10	0.30	0.25			
c	0.10	0.22	0.11			
D	1.80	2.20	2.15			
ш	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	C).650 E	SC			
F	0.40	0.45	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All I	Dimen	sions	in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking. Note:

SOT363

SOT363



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